UNISONIC TECHNOLOGIES CO., LTD

BAS21 DIODE

GENERAL PURPOSE DIODES

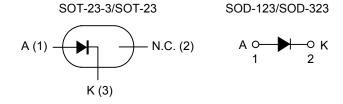
■ DESCRIPTION

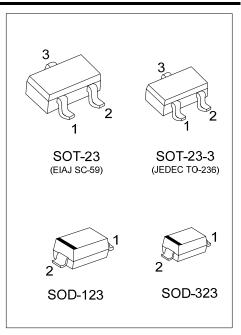
The UTC **BAS21** is a general purpose diode using UTC's planar technology to provide customers with high current capacity and high switching speed.

■ FEATURES

- * High Current Capability
- * High Switching Speed

■ SYMBOL

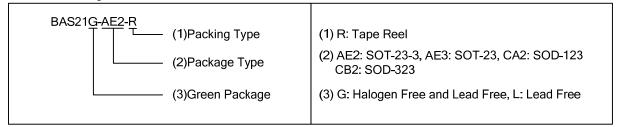




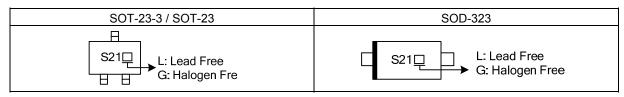
■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BAS21L-AE2-R	BAS21G-AE2-R	SOT-23-3	Α	NC	K	Tape Reel	
BAS21L-AE3-R	BAS21G-AE3-R	SOT-23	Α	NC	K	Tape Reel	
BAS21L-CA2-R	BAS21G-CA2-R	SOD-123	Α	K	NC	Tape Reel	
BAS21L-CB2-R	BAS21G-CB2-R	SOD-323	Α	K	NC	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode NC: No Connection



MARKING



www.unisonic.com.tw 1 of 3

BAS21 DIODE

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage		V_{RRM}	250	V
Continuous Reverse Voltage		V_R	200	V
Continuous Forward Current (Note 1)		I _F	200	mA
Repetitive Peak Forward Current		I _{FRM}	625	mA
Non-Repetitive Peak Forward	t=1µs		9	Α
Current (Square Wave,	t=100µs	I _{FSM}	3	Α
T _J =25 °C Prior to Surge)	t=10ms		1.7	Α
Power Dissipation (T _A =25°C) (Note 1)	SOT-23 SOT-23-3	P _D	250	mW
	SOD-123 SOD-323		410	mW
Junction Temperature		ΤJ	+150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient (Note 1)	SOT-23 SOT-23-3	0	330	K/W	
	SOD-123 SOD-323	$ heta_{JA}$	200	K/W	

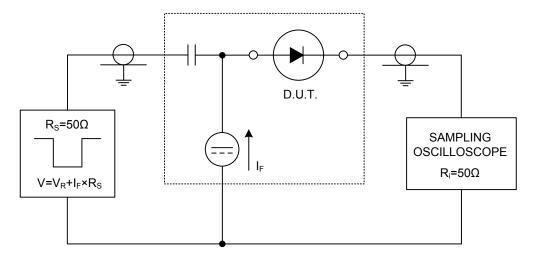
Note: 1. Device mounted on an FR4 printed-circuit board.

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified.)

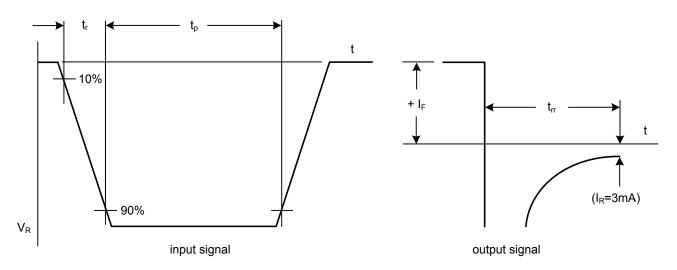
PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Forward Voltage	V _F	I _F =100mA			1	V
		I _F =200mA			1.25	V
Reverse Current	l _D	V _R =200V			100	nA
		V _R =200V, T _J =150°C			100	μA
Diode Capacitance	C_D	f=1MHz, V _R =0			5	pF
Reverse Recovery Time	too	when switched from I_F =30mA to I_R =30mA, R_L =100 Ω , measured at I_R =3mA			50	ns

BAS21 DIODE

TEST CIRCUITS AND WAVEFOMS



Reverse recovery voltage test circuit



Reverse recovery voltage waveforms

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